

Thyristor \ Diode Module

preliminary

$$V_{RRM} = 2 \times 1600 \text{ V}$$

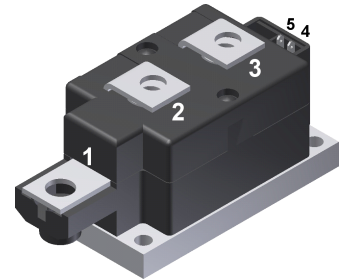
$$I_{TAV} = 260 \text{ A}$$

$$V_T = 1.15 \text{ V}$$

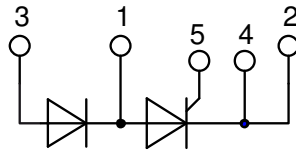
Phase leg

Part number

MCMA265PD1600KB



Backside: isolated



Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al₂O₃-ceramic

Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

Package: Y1

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: Copper internally DCB isolated
- Advanced power cycling

Terms Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office.

Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office.

Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

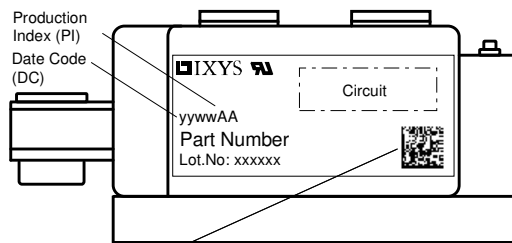
- to perform joint risk and quality assessments;

- the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

| Rectifier | | | Ratings | | | |
|----------------|--|--|--------------------------------|------|-------|-------------------|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
| $V_{RSM/DSM}$ | max. non-repetitive reverse/forward blocking voltage | $T_{VJ} = 25^{\circ}\text{C}$ | | | 1700 | V |
| $V_{RRM/DRM}$ | max. repetitive reverse/forward blocking voltage | $T_{VJ} = 25^{\circ}\text{C}$ | | | 1600 | V |
| I_{RD} | reverse current, drain current | $V_{R/D} = 1600\text{ V}$ | $T_{VJ} = 25^{\circ}\text{C}$ | | 300 | μA |
| | | $V_{R/D} = 1600\text{ V}$ | $T_{VJ} = 140^{\circ}\text{C}$ | | 30 | mA |
| V_T | forward voltage drop | $I_T = 300\text{ A}$ | $T_{VJ} = 25^{\circ}\text{C}$ | | 1.19 | V |
| | | $I_T = 600\text{ A}$ | | | 1.46 | V |
| | | $I_T = 300\text{ A}$ | $T_{VJ} = 125^{\circ}\text{C}$ | | 1.15 | V |
| | | $I_T = 600\text{ A}$ | | | 1.44 | V |
| I_{TAV} | average forward current | $T_C = 85^{\circ}\text{C}$ | $T_{VJ} = 140^{\circ}\text{C}$ | | 260 | A |
| $I_{T(RMS)}$ | RMS forward current | 180° sine | | | 408 | A |
| V_{T0} | threshold voltage | } for power loss calculation only | $T_{VJ} = 140^{\circ}\text{C}$ | | 0.80 | V |
| r_T | slope resistance | | | | 0.75 | m Ω |
| R_{thJC} | thermal resistance junction to case | | | | 0.16 | K/W |
| R_{thCH} | thermal resistance case to heatsink | | | 0.04 | | K/W |
| P_{tot} | total power dissipation | | $T_C = 25^{\circ}\text{C}$ | | 720 | W |
| I_{TSM} | max. forward surge current | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$ | $T_{VJ} = 45^{\circ}\text{C}$ | | 8.50 | kA |
| | | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$ | | 9.18 | kA |
| | | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$ | $T_{VJ} = 140^{\circ}\text{C}$ | | 7.23 | kA |
| | | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$ | | 7.81 | kA |
| I^2t | value for fusing | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$ | $T_{VJ} = 45^{\circ}\text{C}$ | | 361.3 | kA ² s |
| | | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$ | | 350.6 | kA ² s |
| | | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$ | $T_{VJ} = 140^{\circ}\text{C}$ | | 261.0 | kA ² s |
| | | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$ | | 253.4 | kA ² s |
| C_J | junction capacitance | $V_R = 400\text{ V}$ $f = 1\text{ MHz}$ | $T_{VJ} = 25^{\circ}\text{C}$ | | 366 | pF |
| P_{GM} | max. gate power dissipation | $t_p = 30\text{ }\mu\text{s}$ | $T_C = 140^{\circ}\text{C}$ | | 120 | W |
| | | $t_p = 500\text{ }\mu\text{s}$ | | | 60 | W |
| P_{GAV} | average gate power dissipation | | | | 20 | W |
| $(di/dt)_{cr}$ | critical rate of rise of current | $T_{VJ} = 140^{\circ}\text{C}; f = 50\text{ Hz}$ repetitive, $I_T = 750\text{ A}$ | | | 100 | A/ μs |
| | | $t_p = 200\text{ }\mu\text{s}; di_G/dt = 1\text{ A}/\mu\text{s};$ $I_G = 1\text{ A}; V = \frac{2}{3} V_{DRM}$ non-repet., $I_T = 268\text{ A}$ | | | 500 | A/ μs |
| $(dv/dt)_{cr}$ | critical rate of rise of voltage | $V = \frac{2}{3} V_{DRM}$ | $T_{VJ} = 140^{\circ}\text{C}$ | | 1000 | V/ μs |
| | | $R_{GK} = \infty$; method 1 (linear voltage rise) | | | | |
| V_{GT} | gate trigger voltage | $V_D = 6\text{ V}$ | $T_{VJ} = 25^{\circ}\text{C}$ | | 2 | V |
| | | | $T_{VJ} = -40^{\circ}\text{C}$ | | 3 | V |
| I_{GT} | gate trigger current | $V_D = 6\text{ V}$ | $T_{VJ} = 25^{\circ}\text{C}$ | | 150 | mA |
| | | | $T_{VJ} = -40^{\circ}\text{C}$ | | 220 | mA |
| V_{GD} | gate non-trigger voltage | $V_D = \frac{2}{3} V_{DRM}$ | $T_{VJ} = 140^{\circ}\text{C}$ | | 0.25 | V |
| I_{GD} | gate non-trigger current | | | | 10 | mA |
| I_L | latching current | $t_p = 30\text{ }\mu\text{s}$ | $T_{VJ} = 25^{\circ}\text{C}$ | | 200 | mA |
| | | $I_G = 0.45\text{ A}; di_G/dt = 0.45\text{ A}/\mu\text{s}$ | | | | |
| I_H | holding current | $V_D = 6\text{ V}$ $R_{GK} = \infty$ | $T_{VJ} = 25^{\circ}\text{C}$ | | 150 | mA |
| t_{gd} | gate controlled delay time | $V_D = \frac{1}{2} V_{DRM}$ | $T_{VJ} = 25^{\circ}\text{C}$ | | 2 | μs |
| | | $I_G = 1\text{ A}; di_G/dt = 1\text{ A}/\mu\text{s}$ | | | | |
| t_q | turn-off time | $V_R = 100\text{ V}; I_T = 300\text{ A}; V = \frac{2}{3} V_{DRM}$ $T_{VJ} = 125^{\circ}\text{C}$ $di/dt = 10\text{ A}/\mu\text{s}$ $dv/dt = 50\text{ V}/\mu\text{s}$ $t_p = 200\text{ }\mu\text{s}$ | | 200 | | μs |

| Package Y1 | | | Ratings | | | |
|---------------|--|----------------------|---------|------|------|------|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
| I_{RMS} | RMS current | per terminal | | | 600 | A |
| T_{VJ} | virtual junction temperature | | -40 | | 140 | °C |
| T_{op} | operation temperature | | -40 | | 125 | °C |
| T_{stg} | storage temperature | | -40 | | 125 | °C |
| Weight | | | | 680 | | g |
| M_D | mounting torque | | 4.5 | | 7 | Nm |
| M_T | terminal torque | | 11 | | 13 | Nm |
| $d_{Spp/App}$ | creepage distance on surface striking distance through air | terminal to terminal | 16.0 | | | mm |
| $d_{Spb/Apb}$ | | terminal to backside | 16.0 | | | mm |
| V_{ISOL} | isolation voltage | t = 1 second | 4800 | | | V |
| | | t = 1 minute | 4000 | | | V |



Data Matrix: part no. (1-19), DC + PI (20-25), lot.no.# (26-31), blank (32), serial no.# (33-36)

Part description

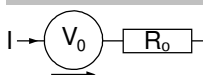
- M = Module
- C = Thyristor (SCR)
- M = Thyristor
- A = (up to 1800V)
- 265 = Current Rating [A]
- PD = Phase leg
- 1600 = Reverse Voltage [V]
- KB = Y1-CU

| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | MCMA265PD1600KB | MCMA265PD1600KB | Box | 3 | 509202 |

Equivalent Circuits for Simulation

* on die level

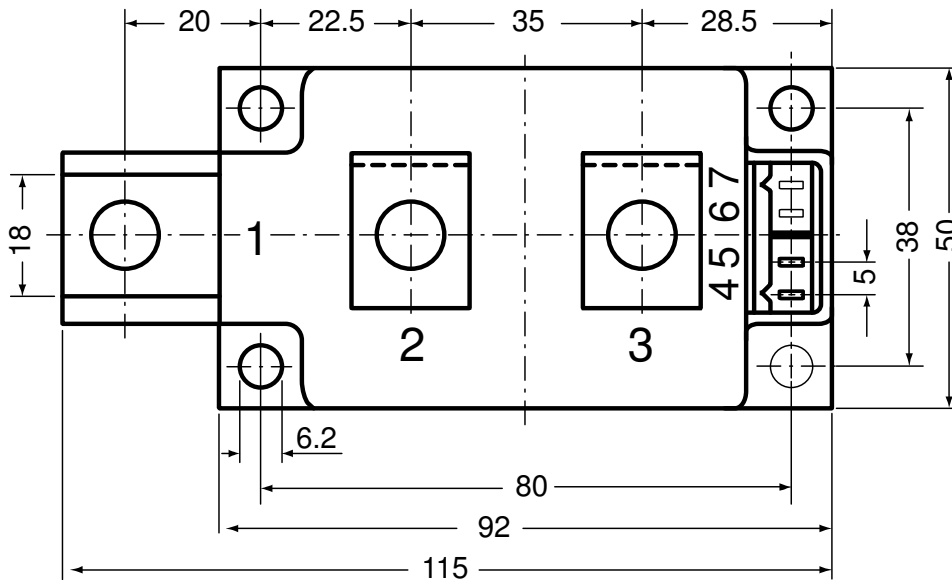
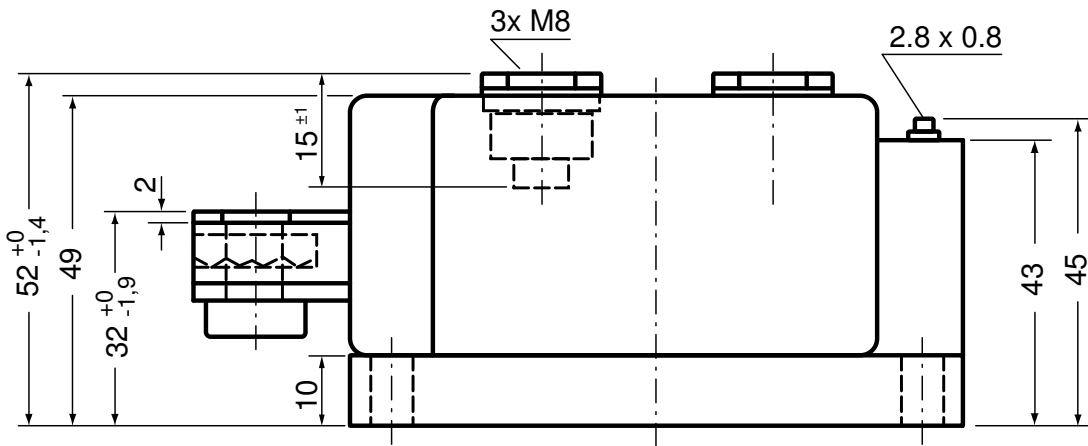
$T_{VJ} = 140\text{ °C}$



Thyristor

| | | | |
|--------------|--------------------|------|----|
| $V_{0\ max}$ | threshold voltage | 0.8 | V |
| $R_{0\ max}$ | slope resistance * | 0.51 | mΩ |

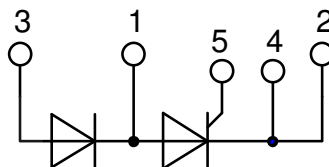
Outlines Y1



Optional accessories for modules

Keyed gate/cathode twin plugs with wire length = 350 mm, gate = white, cathode = red

Type ZY 180L (L = Left for pin pair 4/5)
 Type ZY 180R (R = Right for pin pair 6/7) } UL 758, style 3751



Thyristor

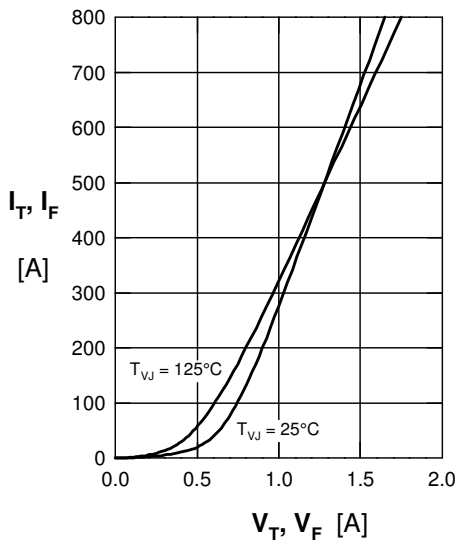


Fig. 1 Forward voltage drop

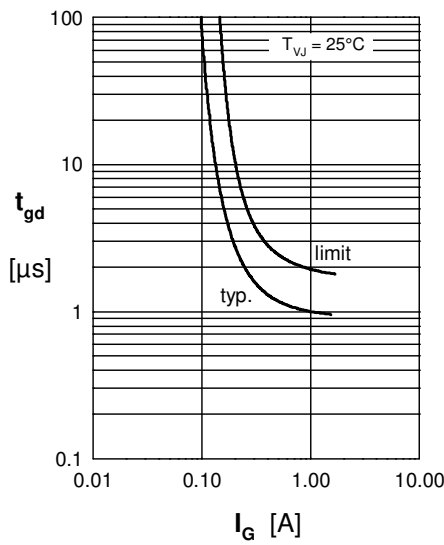


Fig. 2 Gate trigger delay time

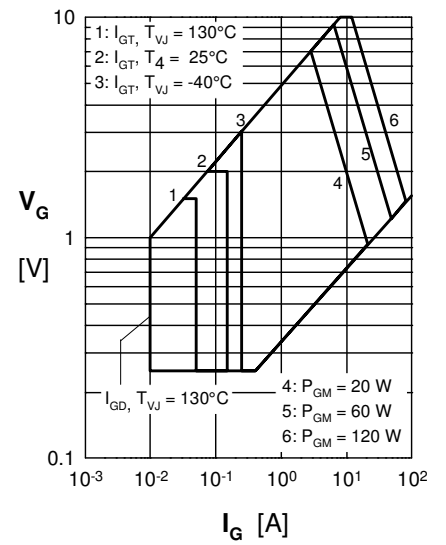


Fig. 3 Gate trigger characteristics

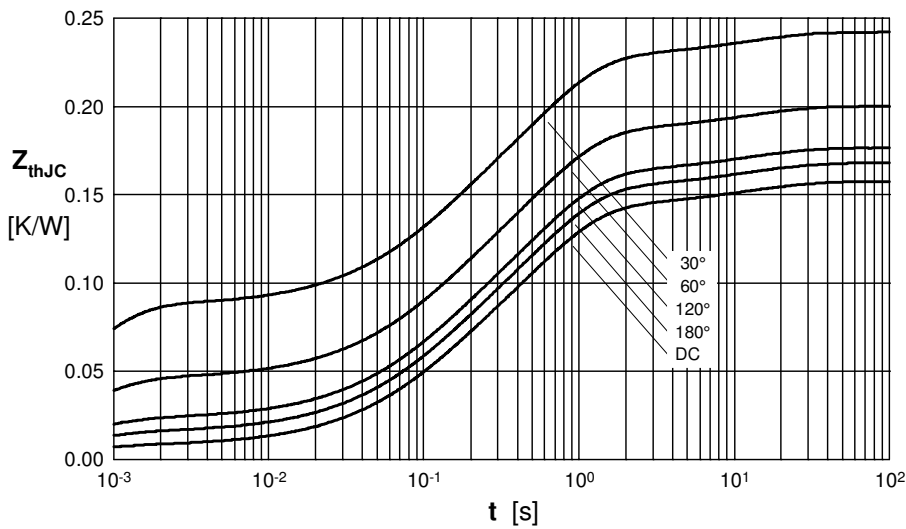


Fig. 4 Transient thermal impedance junction to case (per thyristor/diode)

R_{thJC} for various conduction angles d:

| d | R_{thJC} (K/W) |
|------|------------------|
| DC | 0.157 |
| 180° | 0.168 |
| 120° | 0.177 |
| 60° | 0.200 |
| 30° | 0.243 |

Constants for Z_{th} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|---|-----------------|-----------|
| 1 | 0.0076 | 0.0054 |
| 2 | 0.0406 | 0.098 |
| 3 | 0.0944 | 0.54 |
| 4 | 0.0147 | 12 |